# 2SA1337

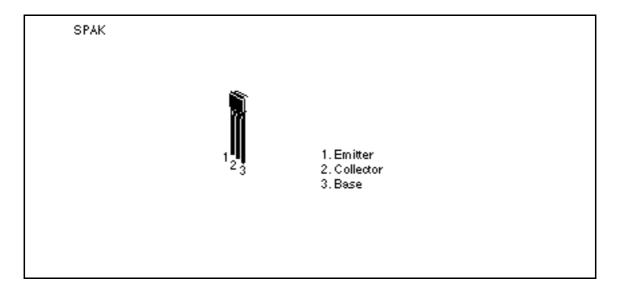
## Silicon PNP Epitaxial

# HITACHI

#### **Application**

- Low frequency low noise amplifier
- · HF amplefier

#### Outline





## 2SA1337

#### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	<b>–</b> 55	V
Collector to emitter voltage	$V_{\text{CEO}}$	<b>–</b> 50	V
Emitter to base voltage	$V_{EBO}$	<b>–</b> 5	V
Collector current	I <sub>c</sub>	-100	mA
Collector power dissipation	P <sub>c</sub>	300	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

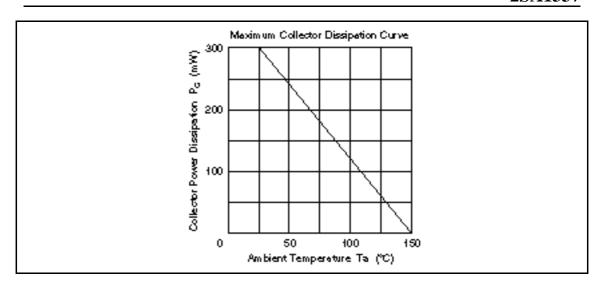
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	<b>–</b> 55	_	_	V	$I_{c} = -10 \ \mu A, \ I_{e} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	<b>-</b> 50	_	_	V	$I_C = -1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	<b>-</b> 5	_	_	V	$I_{E} = -10 \ \mu A, \ I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	-0.5	μA	$V_{CB} = -18 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	-0.5	μΑ	$V_{EB} = -2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	100	_	320		$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Base to emitter voltage	$V_{BE}$	_	_	-0.75	V	$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	-0.2	V	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -1 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	_	200	_	MHz	$V_{CE} = -12 \text{ V}, I_{C} = -2 \text{ mA}$
Collector output capacitance	Cob	_	_	4.5	pF	$V_{CB} = -10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Noise figure	NF	_	1.0	5.0	dB	$V_{CE} = -6 \text{ V}, I_{C} = -0.1 \text{ mA},$ $R_{g} = 1 \text{ k} , f = 1 \text{ kHz}$

Note: 1. The 2SA1337 is grouped by  $h_{\rm FE}$  as follows.

B C 100 to 200 160 to 320

See characteristic curves of 2SA1031.

2SA1337



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